



Small Signal Schottky Diode

Features

- For general purpose applications
- This diode features low turn-on voltage and high break-down voltage. This device is protected by a PN junction guardring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the DO-35 case with type designation BAT46 and in the SOD-123 case with type designation BAT46W.



Mechanical Data

Case: MiniMELF Glass case (SOD-80)

Weight: approx. 31 mg **Packaging Codes/Options:**

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Marking	Remarks
LL46	LL46-GS18 or LL46-GS08	-	Tape and Reel

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	100	V
Forward continuous current	T _{amb} = 25 °C	I _F	150 ¹⁾	mA
Repetitive peak forward current	$t_p < 1 \text{ s, } \delta < 0.5, T_{amb} = 25 \text{ °C}$	I _{FRM}	350 ¹⁾	mA
Surge forward current	$t_p = 10 \text{ ms}, T_{amb} = 25 ^{\circ}\text{C}$	I _{FSM}	750 ¹⁾	mA
Power dissipation ¹⁾	T _{amb} = 80 °C	P _{tot}	200 ¹⁾	mW

¹⁾ Valid provided that electrodes are kept at ambient temperature

Thermal Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R _{thJA}	0.3 ¹⁾	°C/mW
Junction temperature		Tj	125	°C
Ambient operating temperature range		T _{amb}	- 55 to + 125	°C
Storage temperature range		T _S	- 65 to + 150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature

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Electrical Characteristics

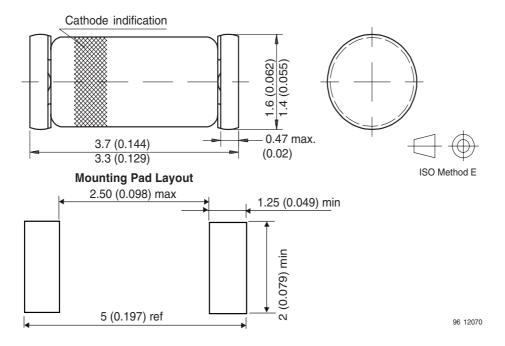
 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	100 μA pulses	V _{(BR)R}	100			V
Leakage current	Pulse test $t_p = 300 \mu s$, $V_R = 1.5 \text{ V}$, $\delta < 2 \%$	I _R			0.5	μА
	Pulse test t_p = 300 μ s, V_R = 1.5 V, T_j = 60 °C, δ < 2 %	I _R			5	μΑ
	Pulse test t_p = 300 μ s, V_R = 10 V, δ < 2 %	I _R			0.8	μΑ
	Pulse test t_p = 300 μ s, V _R = 10 V, T _j = 60 °C, δ < 2 %	I _R			7.5	μА
	Pulse test t_p = 300 μ s, V_R = 50 V, δ < 2 %	I _R			2	μА
	Pulse test t_p = 300 μ s, V_R = 50 V, T_j = 60 °C, δ < 2 %	I _R			15	μА
	Pulse test t_p = 300 μ s, V_R = 75 V, δ < 2 %	I _R			5	μА
	Pulse test t_p = 300 μ s, V _R = 75 V, T _j = 60 °C, δ < 2 %	I _R			20	μА
Forward voltage	Pulse test t_p = 300 μ s, I_F = 0.1 mA, δ < 2 %	V _F			0.25	V
	Pulse test t_p = 300 μ s, I_F = 10 mA, δ < 2 %	V _F			0.45	V
	Pulse test t_p = 300 μ s, I_F = 250 mA, δ < 2 %	V _F			1	V
Diode capacitance	V _R = 0 V, f = 1 MHz	C _{tot}		10		pF
	V _R = 1 V, f = 1 MHz	C _{tot}		6		pF



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Package Dimensions in mm (Inches)



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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